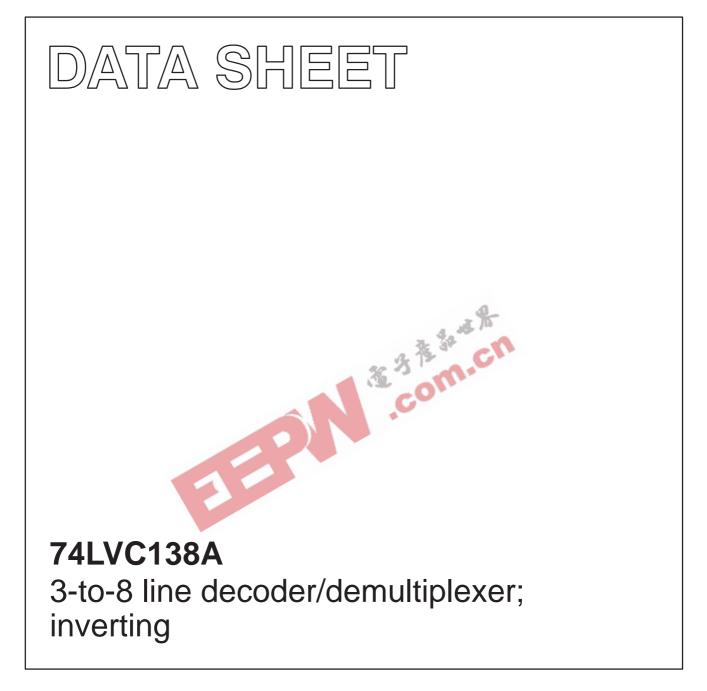
# INTEGRATED CIRCUITS



**Product specification** 

1998 Apr 28



# 74LVC138A

#### **FEATURES**

- Wide supply voltage range of 1.2 to 3.6 V
- In accordance with JEDEC standard no. 8-1A
- Inputs accept voltages up to 5.5 V
- CMOS lower power consumption
- Direct interface with TTL levels
- Demultiplexing capability
- Multiple input enable for easy expansion
- Ideal for memory chip select decoding
- Active LOW mutually exclusive outputs
- Output drive capability 50 Ω transmission lines at 85°C

#### DESCRIPTION

The 74LVC138A is a low-voltage, low-power, high-performance Si-gate CMOS device, superior to most advanced CMOS compatible TTL families.

The 74LVC138A accepts three binary weighted address inputs (A<sub>0</sub>, A1, A2) and when enabled, provides 8 mutually exclusive active LOW outputs ( $\overline{Y}_0$  to  $\overline{Y}_7$ ).

The 74LVC138A features three enable inputs: two active LOW ( $\overline{E}_1$ and  $\overline{E}_2$ ) and one active HIGH (E<sub>3</sub>). Every output will be HIGH unless  $\overline{E}_1$  and  $E_2$  are LOW and  $E_3$  is HIGH.

This multiple enable function allows easy parallel expansion of the 74LV138A to a 1-of-32 (5 lines to 32 lines) decoder with just four 74LV138A ICs and one inverter. The 74LV138A can be used as an eight output demultiplexer by using one of the active LOW enable inputs as the data input and the remaining enable inputs as strobes. Unused enable inputs must be permanently tied to their appropriate active HIGH or LOW state. 34 - 5 %

### QUICK REFERENCE DATA

2500. + + < 9 5 00

$GND = 0 V; I_{amb} = 25^{\circ}C$	$t_r = t_f \le 2.5 \text{ ns}$	A 32	A	
SYMBOL	PARAMETER	CONDITIONS	TYPICAL	UNIT
t <sub>PHL</sub> /t <sub>PLH</sub>	Propagation delay An to $\overline{Y}n$ , E <sub>3</sub> to $\overline{Y}n$ , $\overline{E}n$ to $\overline{Y}n$	C <sub>L</sub> = 50 pF; V <sub>CC</sub> = 3.3 V	3.5 3.5	ns
Cl	Input capacitance		5.0	pF
C <sub>PD</sub>	Power dissipation capacitance per package	$V_{CC} = 3.3 V$ Notes 1 and 2	44	pF

#### NOTES:

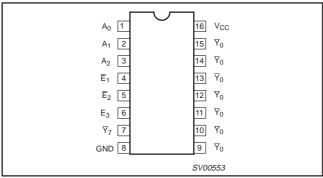
- 1.  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ )
  - $P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum (C_L \times V_{CC}^2 \times f_o)$  where:
  - $f_i$  = input frequency in MHz;  $C_L$  = output load capacity in pF;  $f_o$  = output frequency in MHz;  $V_{CC}$  = supply voltage in V;

  - $\sum (C_L \times V_{CC}^2 \times f_0) =$  sum of the outputs.
- 2. The condition is  $V_I = GND$  to  $V_{CC}$

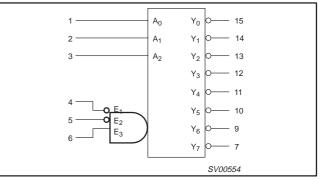
#### **ORDERING INFORMATION**

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	PKG. DWG. #
16-Pin Plastic SO	–40°C to +85°C	74LVC138A D	74LVC138A D	SOT109-1
16-Pin Plastic SSOP Type II	–40°C to +85°C	74LVC138A DB	74LVC138A DB	SOT338-1
16-Pin Plastic TSSOP Type I	–40°C to +85°C	74LVC138A PW	74LVC138APW DH	SOT403-1

#### **PIN CONFIGURATION**



#### LOGIC DIAGRAM

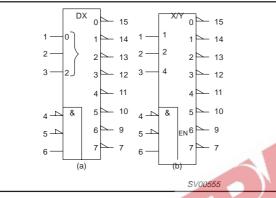


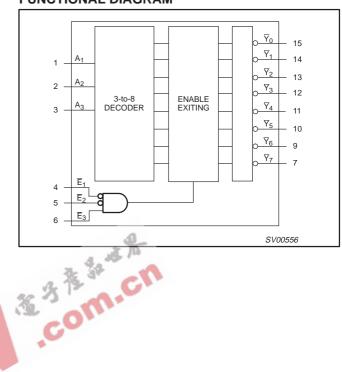
### 74LVC138A

#### **PIN DESCRIPTION**

PIN NUMBER	SYMBOL	NAME AND FUNCTION
1, 2, 3	A <sub>0</sub> to A <sub>2</sub>	Address inputs
4, 5	$\overline{E}_1, \overline{E}_2$	Enable inputs (active LOW)
6	E <sub>3</sub>	Enable inputs (active HIGH)
15, 14, 13, 12, 11, 10, 9, 7	$\overline{Y}_0$ to $\overline{Y}_7$	Outputs
8	GND	Ground (0 V)
16	V <sub>CC</sub>	Positive supply voltage

### LOGIC SYMBOL (IEEE/IEC)





#### FUNCTIONAL DIAGRAM

#### **FUNCTION TABLE**

	INPUTS								OUT	PUTS			
E <sub>1</sub>	E <sub>2</sub>	E <sub>3</sub>	Ao	A <sub>1</sub>	A <sub>2</sub>	Υ <sub>0</sub>	Υ <sub>1</sub>	$\overline{Y}_2$	$\overline{Y}_3$	$\overline{Y}_4$	$\overline{Y}_5$	Υ <sub>6</sub>	Υ <sub>7</sub>
Н	Х	Х	X	Х	Х	Н	Н	н	Н	Н	Н	Н	Н
Х	Н	Х	Х	Х	Х	н	н	н	н	н	н	н	н
Х	Х	L	Х	Х	Х	н	н	н	н	н	н	н	н
L	L	Н	L	L	L	L	Н	Н	Н	Н	Н	Н	н
L	L	н	Н	L	L	н	L	н	н	н	н	н	н
L	L	Н	L	н	L	н	н	L	н	н	н	н	н
L	L	Н	н	н	L	н	н	н	L	н	н	н	н
L	L	Н	L	L	Н	Н	Н	Н	Н	L	Н	Н	Н
L	L	Н	Н	L	н	н	н	н	н	н	L	н	н
L	L	н	L	н	н	н	н	н	н	н	н	L	н
L	L	Н	Н	Н	Н	н	н	н	Н	н	н	н	L

NOTES:

H = HIGH voltage level

L = LOW voltage level

X = don't care

### 74LVC138A

#### LIMITS SYMBOL CONDITIONS UNIT PARAMETER MIN MAX DC supply voltage (for max. speed performance) 2.7 3.6 V $V_{CC}$ DC supply voltage (for low-voltage applications) 1.2 3.6 VI DC input voltage range 0 5.5 V DC output voltage range; output HIGH or LOW state 0 V<sub>CC</sub> V VI/O DC input voltage range; output 3-State 0 5.5 Tamb Operating free-air temperature range -40 +85 °C $V_{CC} = 1.2$ to 2.7V 0 20 ns/V t<sub>r</sub>, t<sub>f</sub> Input rise and fall times $V_{CC} = 2.7$ to 3.6V 0 10

#### **RECOMMENDED OPERATING CONDITIONS**

#### **ABSOLUTE MAXIMUM RATINGS<sup>1</sup>**

In accordance with the Absolute Maximum Rating System (IEC 134). Voltages are referenced to GND (ground = 0V)

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V <sub>CC</sub>	DC supply voltage	1- <sup>36</sup> K	-0.5 to +6.5	V
I <sub>IK</sub>	DC input diode current	V <sub>1</sub> < 0	-50	mA
VI	DC input voltage	Note 2	-0.5 to +6.5	V
I <sub>OK</sub>	DC output diode current	$V_0 > V_{CC}$ or $V_0 < 0$	±50	mA
M	DC output voltage; output HIGH or LOW	Note 2	-0.5 to V <sub>CC</sub> +0.5	V
V <sub>I/O</sub>	DC input voltage; output 3-State	Note 2	-0.5 to 6.5	v
Ι <sub>Ο</sub>	DC output source or sink current	$V_{O} = 0$ to $V_{CC}$	±50	mA
I <sub>GND</sub> , I <sub>CC</sub>	DC V <sub>CC</sub> or GND current		±100	mA
T <sub>stg</sub>	Storage temperature range		-65 to +150	°C
P <sub>TOT</sub>	Power dissipation per package – plastic mini-pack (SO) – plastic shrink mini-pack (SSOP and TSSOP)	above +70°C derate linearly with 8 mW/K above +60°C derate linearly with 5.5 mW/K	500 500	mW

NOTES:

 Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

2. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

### 74LVC138A

#### DC ELECTRICAL CHARACTERISTICS

Over recommended operating conditions. Voltages are referenced to GND (ground = 0V).

			L				
SYMBOL	PARAMETER TEST CONDITIONS		Temp = -	Temp = -40°C to +85°C			
			MIN	TYP <sup>1</sup>	MAX		
V		$V_{CC} = 1.2V$	V <sub>CC</sub>			v	
V <sub>IH</sub>	HIGH level input voltage	$V_{CC} = 2.7$ to $3.6V$	2.0			V	
V		$V_{CC} = 1.2V$			GND	v	
V <sub>IL</sub>	LOW level input voltage	$V_{CC} = 2.7$ to $3.6V$			0.8		
		$V_{CC}$ = 2.7V; $V_I$ = $V_{IH}$ or $V_{IL}$ ; $I_O$ = -12mA	$V_{CC} - 0.5$				
		$V_{CC} = 3.0V$ ; $V_I = V_{IH}$ or $V_{IL}$ ; $I_O = -100\mu A$	$V_{CC} - 0.2$	V <sub>CC</sub>		v	
V <sub>OH</sub>	HIGH level output voltage	$V_{CC}$ = 3.0V; $V_I$ = $V_{IH}$ or $V_{IL}$ ; $I_O$ = -12mA	$V_{CC} - 0.6$				
		$V_{CC} = 3.0V$ ; $V_I = V_{IH}$ or $V_{IL}$ ; $I_O = -24mA$	$V_{CC} - 1.0$				
		$V_{CC} = 2.7V$ ; $V_I = V_{IH}$ or $V_{IL}$ ; $I_O = 12mA$			0.40		
V <sub>OL</sub>	LOW level output voltage	$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL}; I_O = 100 \mu A$		GND	0.20	V	
		$V_{CC} = 3.0V; V_{I} = V_{IH} \text{ or } V_{IL}; I_{O} = 24mA$			0.55		
łı	Input leakage current	$V_{CC} = 3.6V; V_{I} = 5.5V \text{ or GND}$		±0.1	±5	μΑ	
I <sub>CC</sub>	Quiescent supply current	$V_{CC} = 3.6V; V_I = V_{CC} \text{ or GND}; I_O = 0$		0.1	10	μΑ	
Δl <sub>CC</sub>	Additional quiescent supply current per input pin	$V_{CC} = 2.7V$ to 3.6V; $V_I = V_{CC} - 0.6V$ ; $I_O = 0$		5	500	μΑ	

NOTE:

1. All typical values are at  $V_{CC} = 3.3V$  and  $T_{amb} = 25^{\circ}C$ .

#### **AC CHARACTERISTICS**

GND = 0 V;  $t_r = t_f \le 2.5 \text{ ns}$ ;  $C_L = 50 \text{ pF}$ ;  $R_L = 500\Omega$ ;  $T_{amb} = -40^{\circ}\text{C}$  to  $+85^{\circ}\text{C}$ 

						LIMITS					
SYMBOL	PARAMETER	WAVEFORM	Vc	<sub>C</sub> = 3.3V ±0	.3V	V <sub>CC</sub> =	= 2.7V	UNIT			
			MIN	TYP <sup>1</sup>	MAX	MIN	MAX				
t <sub>PHL</sub> /t <sub>PLH</sub>	Propagation delay $A_n$ to $\overline{Y}_n$	Figure 1, 3	1.5	3.5	5.8	1.5	6.8	ns			
t <sub>PHL</sub> /t <sub>PLH</sub>	Propagation delay $E_3$ to $\overline{Y}_n$	Figure 1, 3	1.5	3.6	5.8	1.5	6.8	ns			
t <sub>PHL</sub> /t <sub>PLH</sub>	Propagation delay $E_n$ to $\overline{Y}_n$	Figure 2, 3	1.5	3.5	5.8	1.5	6.8	ns			

NOTE:

1. These typical values are at V\_{CC} = 3.3V and T\_{amb} = 25°C.

### 74LVC138A

S₁

VCC

D.U.T.

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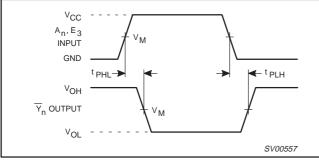
\_ 2 \* V<sub>CC</sub>

O Open ○ GND

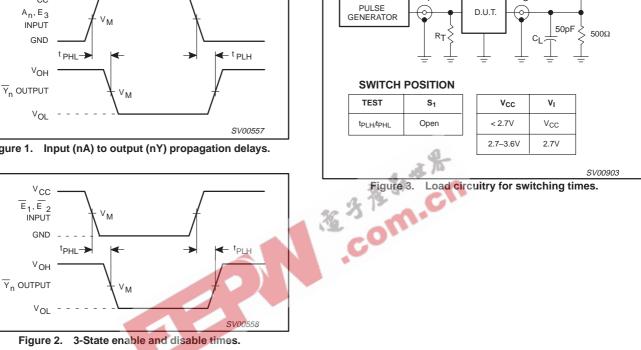
 $500\Omega$ 

#### **AC WAVEFORMS**

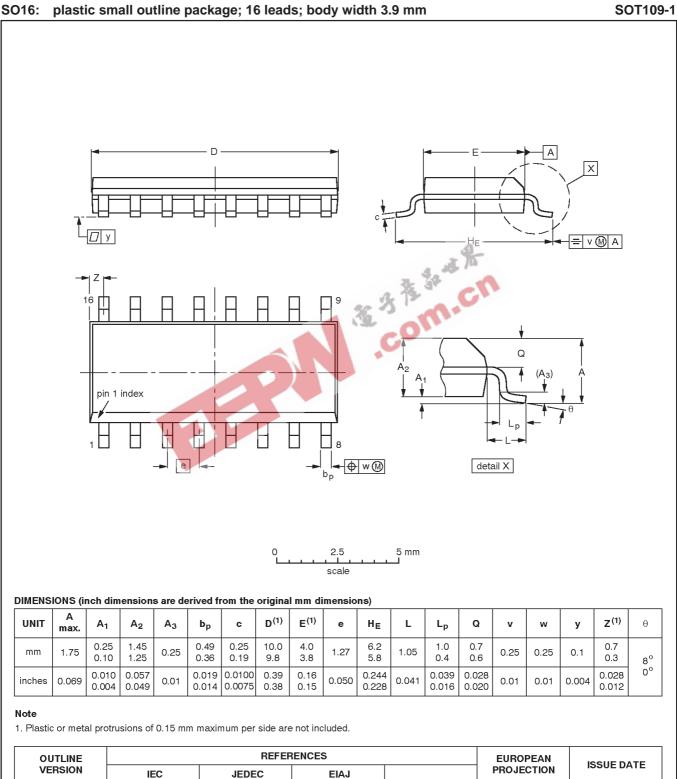
 $V_M$  = 1.5 V at  $V_{CC}$   $\geq\,2.7$  V  $V_M$  = 0.5 •  $V_{CC}$  at  $V_{CC}$  < 2.7 V  $V_{OL}$  and  $V_{OH}$  are the typical output voltage drop that occur with the output load.







**TEST CIRCUIT** 



SO16:

SOT109-1

076E07S

MS-012AC

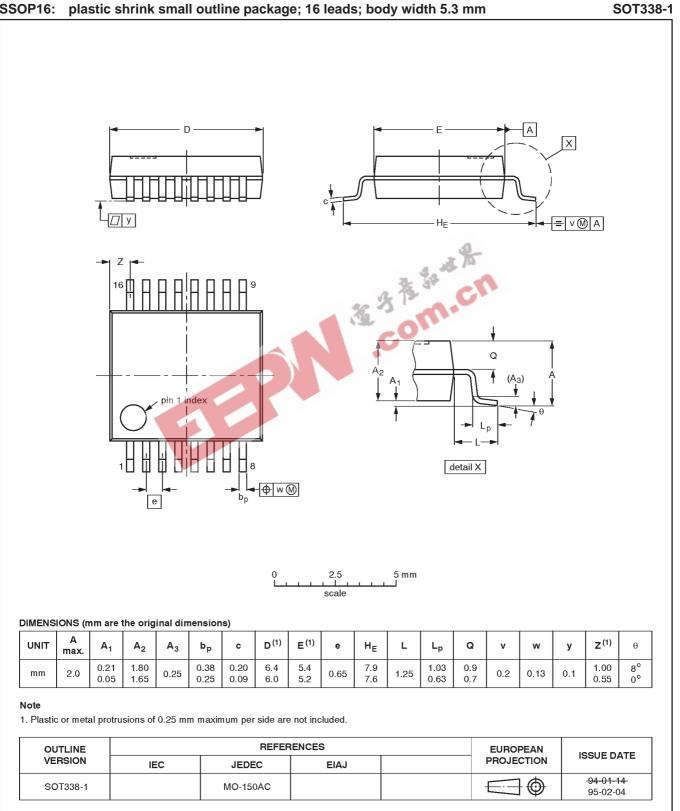
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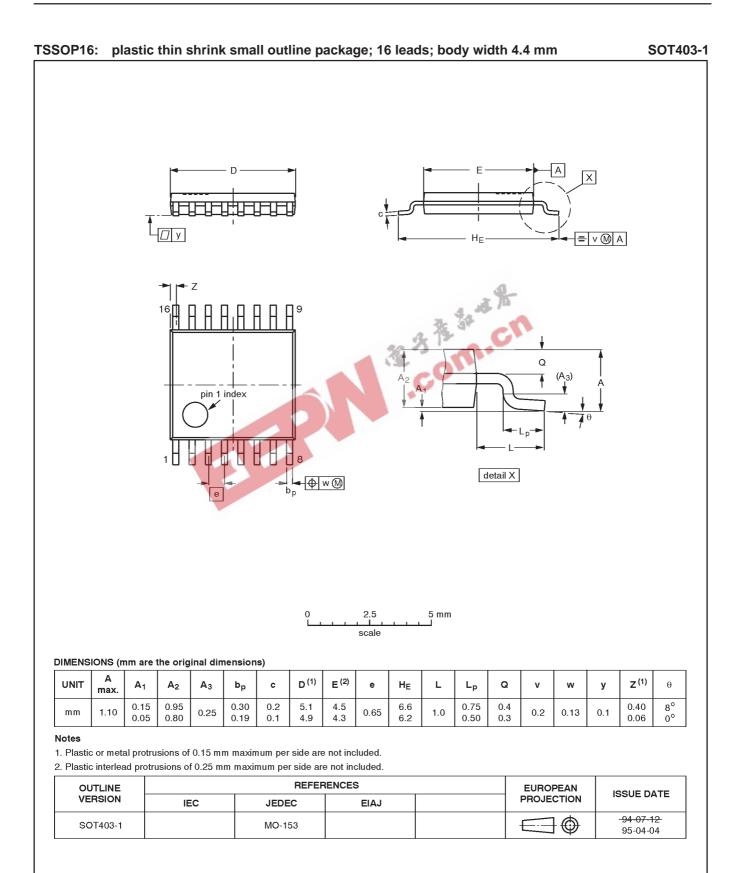
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**F**---



plastic shrink small outline package; 16 leads; body width 5.3 mm SSOP16:



# 74LVC138A

### 74LVC138A

#### Data sheet status

Data sheet status	Product status	Definition [1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
Preliminary specification	Qualification	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make chages at any time without notice in order to improve design and supply the best possible product.
Product specification	Production	This data sheet contains final specifications. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.

[1] Please consult the most recently issued datasheet before initiating or completing a design.

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Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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print code Document order number:

PHILIPS

Date of release: 07-98 9397-750-04493

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